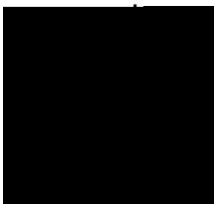
F	2017-4				
G	2020-4-21	2	IEBO ICEO		

Silicon PNP transistor in a SOT-23 Plastic Package.

$V_{CE(sat)}$。

High current gain, Low collector-emitter saturation voltage.

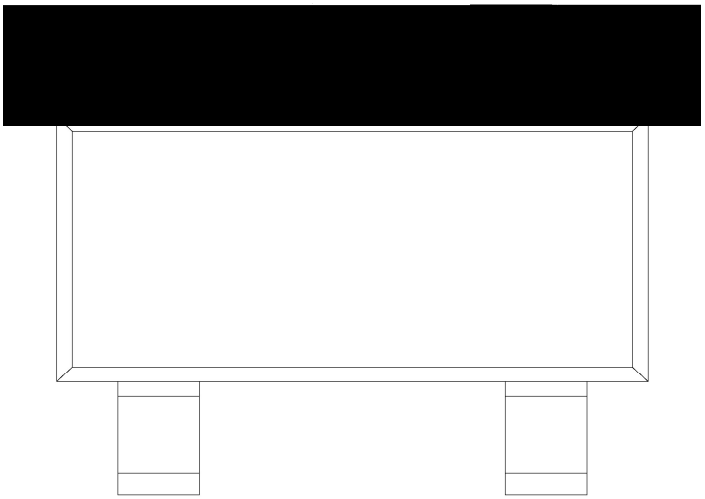
General power amplifier application.



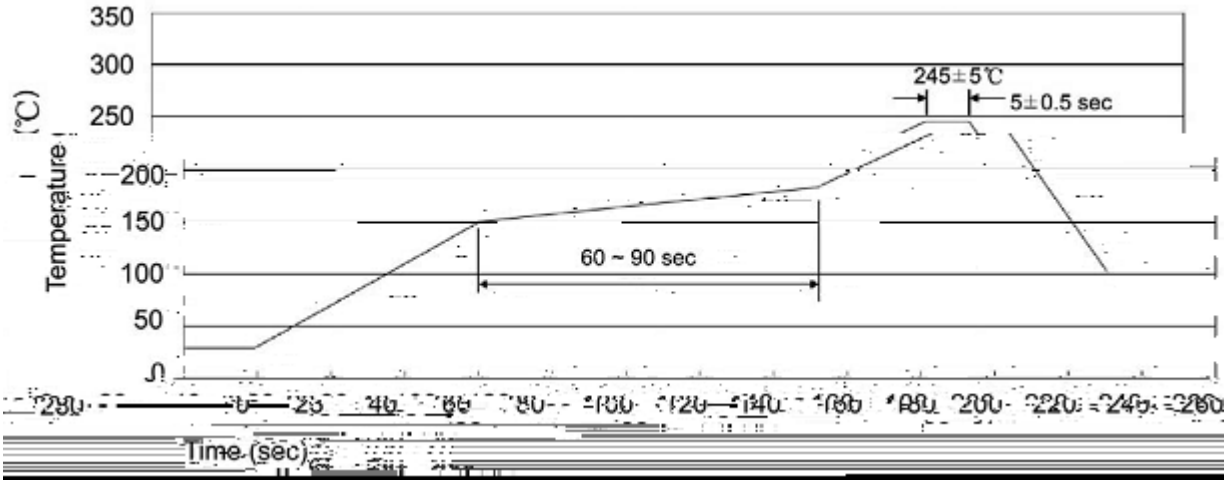


PIN1 Base PIN 2 Emitter PIN 3 Collector

h_{FE} Classifications Symbol	A	B	C
h_{FE} Range	125～250	220～475	420～800
Marking	H3J	H3K	H3L



Temperature Profile for IR Reflow Soldering(Pb-Free)



	Note:
1 25 150 60 90sec;	1.Preheating:25~150 , Time:60~90sec.
2. 245±5 5±0.5sec;	2.Peak Temp.:245±5 , Duration:5±0.5sec.
3 2 10 /sec.	3. Cooling Speed: n